



PATENT

IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

Applicant: Bo Su Chen, et al.

Serial No.: 10/622,042

Examiner: unknown

Filing Date: July 17, 2003

Group Art: unknown

For: OPTICAL COUPLING SYSTEM

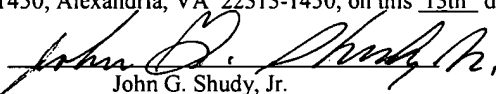
Docket No.: H0004315 (1139.1131101)

TRANSMITTAL SHEET

Assistant Commissioner for Patents
PO Box 1450
Alexandria, VA 22313-1450

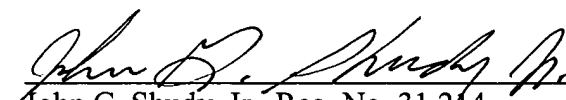
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By:


John G. Shudy, Jr.

We are transmitting herewith the attached:

- ☒ Information Disclosure Statement, Form PTO-1449 and 89 cited non-US patent references.
- ☒ Please charge any deficiencies or credit any overpayment in the enclosed fees to Deposit Account No. 50-0413.


John G. Shudy, Jr., Reg. No. 31,214
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INFORMATION DISCLOSURE STATEMENT (37 C.F.R. §1.97(b))

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By:

John G. Shudy, Jr.

Dear Sir:

With regard to the above-identified application, the items of information listed on the enclosed Form 1449 are brought to the attention of the Examiner.

This statement should be considered because it is submitted before the mailing date of a first Office Action on-the-merits. Accordingly, no fee is due for consideration of the items listed on the enclosed Form 1449.

In accordance with 37 C.F. R. §1.98(a)(2), a copy of each non-US patent or other information listed on the enclosed Form 1449 is provided.

No representation is intended to be made hereby that any of the cited references establishes, by itself or in combination with other information, a prima facie case of unpatentability of any claim of the present case.

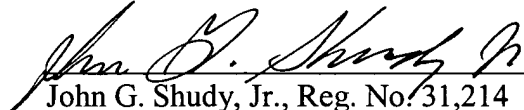
Consideration of the items listed is respectfully requested. Pursuant to the provisions of M.P.E.P. 609, it is requested the Examiner return a copy of the attached Form 1449, marked as being considered and initialed by the Examiner, to the undersigned with the next official communication.

Respectfully submitted,

Bo Su Chen, et al.

By their attorney,

Dated: 11/13/03


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FORM PTO-1449



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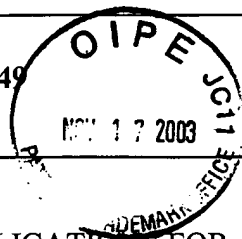
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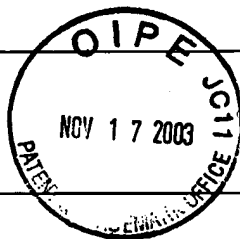
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| | U.S. Patent Application Serial No. 09/751,423, filed December 29, 2000, entitled "Spatially Modulated Reflector for an Optoelectronic Device". |

EXAMINER:

DATE CONSIDERED:

EXAMINER: Initial if citation considered, whether or not citation is in conformance with MPEP 609; draw line through citation if not in conformance and not considered. Include copy of this form with next communication to applicant.



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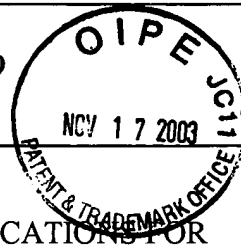
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	6,487,230	11/26/2002	Boucart et al.			
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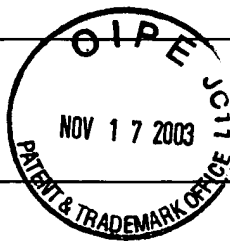
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